On the importance of producing small impedance particles with prescribed boundary impedance

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Abstract

The problem of practical preparing small impedance particles with a prescribed boundary impedance is formulated and its importance in physics and technology is discussed. It is shown that if this problem is solved then one can easily prepare materials with a desired refraction coefficient and materials with a desired radiation pattern.

1 Introduction

In this section the basic problem of practical preparing (producing, manufacturing) of small impedance particles is discussed. Wave scattering by many small impedance particles is developed in [\[3\]](#page-3-0), where the basic physical assumption is $a \ll d \ll \lambda$. Here a is the characteristic size of the small particles, d is the minimal distance between neighboring particles, and λ is the wave length in the medium. We refer for this theory to [\[3\]](#page-3-0). It is proved there that if one prepares many small particles with prescribed boundary impedance and embed these particles with a specified in [\[3\]](#page-3-0) density in a given material, then one obtains a material whose refraction coefficient approximates any desired refraction coefficient with an arbitrary small error. In particular, one can create meta-materials. How to embed small particles into a given material physicists know. Therefore the basic practical problem of preparing many small impedance particles with prescribed boundary impedance is of great interest both technologically and physically.

In section 2 the basic definitions are given. It is explained what a small particle is, what an impedance particle is, what a boundary impedance is.

In section 3 a recipe for creating materials with a desired refraction coefficient is formulated. This recipe is taken from [\[3\]](#page-3-0).

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2 Basic definitions

Let $D_1 \subset \mathbb{R}^3$ be a bounded domain with a connected smooth boundary S_1 , $D'_1 := \mathbb{R}^3 \setminus D_1$ be the unbounded exterior domain and S^2 be the unit sphere in \mathbb{R}^3 .

Consider the scattering problem:

$$
(\nabla^2 + k^2 n_0^2)u = 0 \quad in \quad D'_1, \qquad u_N = \zeta_1 u \quad on \quad S_1, \qquad u = e^{ik\alpha \cdot x} + v,\tag{1}
$$

where $k > 0$ is the wave number, a constant, $\alpha \in S^2$ is a unit vector in the direction of the propagation of the incident plane wave $e^{ik\alpha x}$, N is the unit normal to S_1 pointing out of D_1, u_N is the normal derivative of u, ζ_1 is the boundary impedance, $\text{Im}\zeta_1 \leq 0, n_0 > 0$ is the refraction coefficient of the small impedance particle D , n_0 is a constant, the scattered field v satisfies the radiation condition

$$
v_r - ikv = o\left(\frac{1}{r}\right), \quad r := |x| \to \infty.
$$
 (2)

The scattering amplitude $A(\beta, \alpha, k)$ is defined by the following formula:

$$
v = A(\beta, \alpha, k) \frac{e^{ikr}}{r} + o\left(\frac{1}{r}\right), \quad r := |x| \to \infty, \quad \frac{x}{r} = \beta,
$$
 (3)

where $\alpha, \beta \in S^2$, β is the direction of the scattered wave, α is the direction of the incident wave. A particle of a charcteristic size a is called small if it is much smaller than the wave length, $kn_0a \ll 1$.

The function $A(\beta, \alpha, k)$ is called the scattering amplitude. It is known (see [\[1\]](#page-3-1), p.25, or [\[2\]](#page-3-2)) that the solution to the scattering problem [\(1\)](#page-1-0)-[\(3\)](#page-1-1) does exist and is unique.

If there are many small impedance particles D_j , embedded in a bounded domain D filled with material whose refraction coefficient is n_0 , then the wave scattering problem can be formulated as follows:

$$
(\nabla^2 + k^2 n_0^2)u = 0 \quad in \quad D \tag{4}
$$

$$
u_N = \zeta_m u \quad on \quad S_m, \quad 1 \le m \le M,\tag{5}
$$

$$
u = u_0(x) + v,\tag{6}
$$

where the scattered field v satisfies the radiation condition, $\text{Im}\zeta_m \leq 0$, M is the total number of the embedded particles. The incident field u_0 is assumed known. It satisfies equation [\(4\)](#page-1-2) in \mathbb{R}^3 , and as was noted earlier, $n_0 = 1$ in D'. For simplicity we assume that all small particles are of the same characteristic size a.

Let G be the Green's function of the scattering problem in the absence of the embedded particles. Outside D the refraction coefficient assume to be equal to 1.Assume that the distribution of small particles is given by the formula

$$
\mathcal{N}(\Delta) = \frac{1}{a^{2-\kappa}} \int_{\Delta} N(x) dx [1 + o(1)], \quad a \to 0,
$$
\n(7)

where $\mathcal{N}(\Delta)$ is the number of particles in an arbitrary open subset of D, $N(x) \geq 0$ is a given continuous function, $\kappa \in [0, 1)$ is a number, and the boundary impedance is defined as follows:

$$
\zeta_m = \frac{h_m}{a^{\kappa}},\tag{8}
$$

where Im $h_m \leq 0$, $h_m := h(x_m)$, $x_m \in D_m$ is an arbitrary point and $h(x)$ is a given continuous function in D. This function, number κ and the function $N(x)$ can be chosen by the experimenter. It is proved in [\[3\]](#page-3-0). p. 48, that the field u in D satisfies, as $a \to 0$, the following integral equation:

$$
u(x) = u_0(x) - c_0 \int_D G(x, y)h(y)N(y)dy, \quad c_0 := \mathcal{S}/a^2,
$$
\n(9)

where S is the surface area of a small particle, $h(x)$ and $N(x)$ are defined in [\(7\)](#page-1-3)-[\(8\)](#page-1-4). For simplicity we assume here that S is the same for all small particles. It follows from [\(9\)](#page-2-0) that the new refraction coefficient in D , which one gets after embedding many small impedance particles, is

$$
n(x) = [n_0^2 - c_0 k^{-2} h(x) N(x)]^{1/2}.
$$
\n(10)

Since $h(x)$ and $N(x)$ are at our disposal, one can get by formula [\(10\)](#page-2-1) any desirable refraction coefficient, such that $\text{Im} n^2(x) \geq 0$.

Why the equation [\(5\)](#page-1-5) should make sense physically regardless of the size of the particle? because a problem whose solution exists and is unique must have sense physically.

Why the small impedance particles with a prescribed boundary impedance should exist?

Because the particles with $\zeta = \infty$, acoustically hard particles, do exist; the particles with $\zeta = 0$, acoustically hard particles, do exist. Small particles with any "intermediate" value of the boundary impedance should also exist. The problem we raise is how to produce practically (fabricate) such particles.

3 Recipe for creating material with a desired refraction coefficient

Let us formulate the result in the following theorem:

Theorem 1. Given $n_0^2(x)$ and a bounded domain Ω , one can create in Ω a material with a desired refraction coefficient $n(x)$, $Imn^2(x) \geq 0$, by embedding $M = O(\frac{1}{a^{2}})$ $rac{1}{a^{2-\kappa}}$) small impedance particles according to the distribution law [\(7\)](#page-1-3). The refraction coefficient $n_a(x)$, corresponding to a finite a, approximates the desired refraction coefficient $n(x)$ in the sense

$$
\lim_{a \to 0} n_a(x) = n(x). \tag{11}
$$

The functions $h(x)$ and $N(x)$ defined in [\(7\)](#page-1-3)-[\(8\)](#page-1-4) are found by the Steps 1, 2 of the Recipe formulated below; see als p. 53 in [\[3\]](#page-3-0).

Finally, let us discuss briefly the possibility to create material with negative refraction coefficient. By formulas $(3.1.1)$ and $(3.1.2)$ in [\[3\]](#page-3-0) one gets $n(x) < 0$ if the argument of $n_0^2(x) - k^{-2}c_0N(x)h(x)$ is equal to 2π . Assume that $n_0^2(x) > 0$. We know that $k^{-2}cN(x) \ge 0$. Let us take $h(x) = |h(x)|e^{i\varphi}$, where $\varphi > 0$ is very small, that is, $\text{Im } h(x) \ge 0$ and $\text{Im } h(x)$ is very small. One proves (see also [\[3\]](#page-3-0), p.52) that equation [\(9\)](#page-2-0) is uniquely solvable for $\text{Im}h \geq 0$ sufficiently small. For such $h(x)$ one has $\arg(n_0^2(x) - k^{-2}c_0N(x)h(x))$ is very close to 2π and the square root in [\(10\)](#page-2-1) is negative, provided that $\text{Re}(n_0^2(x) - k^{-2}c_0N(x)h(x)) > 0$. This argument show s that it is possible to create materials with negative refraction coefficient

 $n(x)$ by embedding in a given material many small particles with properly chosen boundary impedances.

A recipe for creating materials

Problem 1. Given a material with known $n_0(x)$ in a bounded domain D and $n_0(x) = 1$ in D' , one wants to create in D a material with a desired $n(x)$.

Step 1. Given $n_0^2(x)$ and $n^2(x)$, calculate $p(x) := k^2[n_0^2(x) - n^2(x)]$. This is a trivial step.

Step 2. Given $p(x)$ calculate $h(x)$ and $N(x)$ from the equation $p(x) = c_0h(c)N(x)$. The constant c_0 one can take to be $c = 4\pi$ if the small particles are balls of radius a. This we can assume without loss of generality if we are interested in creating materials with a desired refraction coefficient.

There are infinitely many solutions h and N to the above equation. For example, one can fix arbitrarily $N(x) > 0$ in D, $N(x) = 0$ in D', and find $h(x) = h_1(x) + ih_2(x)$ by the formulas $h_1(x) = \frac{p_1(x)}{4\pi N(x)}$, $h_2(x) = \frac{p_2(x)}{4\pi N(x)}$. Here $p_1(x) = \text{Rep}(x)$, $p_2(x) = \text{Imp}(x)$.

Note that $\text{Im}n^2(x) \ge 0$ implies $\text{Im}h(x) \le 0$, so our assumption $\text{Im}h(x) \le 0$ is satisfied. For example, one may take $N(x) = \text{const} > 0$.

Step 2 is also trivial.

Step 3. Given $N(x)$ and $h(x) = h_1(x) + ih_2(x)$, distribute $M = O(\frac{1}{a^2})$ $rac{1}{a^{2-\kappa}}$) small impedance balls of radius α in the bounded region D according to the distribution law [\(7\)](#page-1-3), where $\kappa \in [0, 1)$ is the number (parameter) that can be chosen by the experimenter. Note that condition $d \gg a$ is satisfied automatically for the distribution law [\(7\)](#page-1-3). Indeed, if d is the minimal distance between neighboring particles, then there are at most $\frac{1}{d^3}$ particles in a cube with the unit side, and since D is a bounded domain there are at most $\tilde{O}(\frac{1}{d^2})$ $\frac{1}{d^3}$) of small particles in D. On the other hand, by the distribution law [\(7\)](#page-1-3) one has $\mathcal{N}(D) = O(\frac{1}{a^2})$ $rac{1}{a^{2-\kappa}}$). Thus $O(\frac{1}{d^3})$ $\frac{1}{d^3}$) = $O(\frac{1}{a^2})$ $\frac{1}{a^{2-\kappa}}$). Therefore $d = O\left(a^{\frac{2-\kappa}{3}}\right)$. Consequently, condition $a \ll d \ll \lambda$ is satisfied, $\lambda = \frac{2\pi}{kn}$ $\frac{2\pi}{kn_0}$. Moreover $\lim_{a\to 0} \frac{a}{d(a)} = 0$.

References

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